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Open-Channel SSDs for Host-Based Optimization

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A brief of AliFlash

AliFlash V1

- Host-Based PCIe SSD
- Deployed since 2016
- > 50k pcs

AliFlash V2

- Device based NVMe SSD
- Deployed since 2017

AliFlash V3

- Open Channel SSD
- Volume ramping up
- Targeting DB/RDS/ Search/EBS etc.

First Productionized OC-SSD

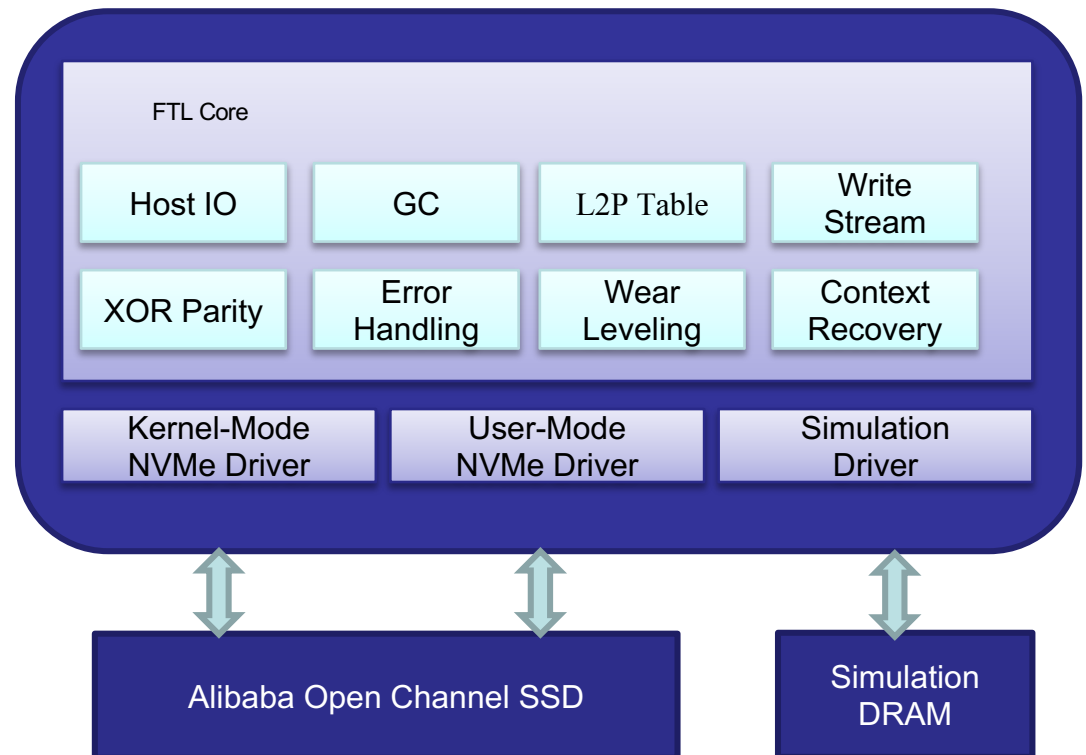
- Alibaba's home-developed Open Channel SSD - AliFlash V3
- Deployment ongoing in data centers
- Major milestone since the announcement of Alibaba's Open Channel SSD Architecture in FAST'2018
- Collaborating with multiple SSD vendors to build an ecosystem



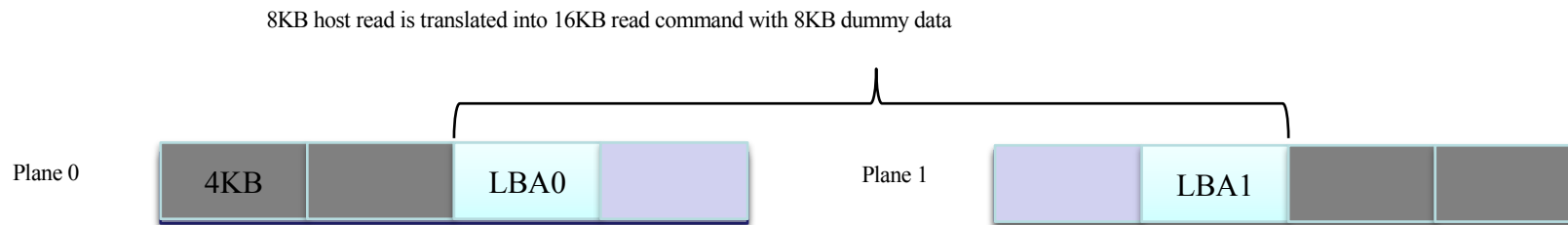


Block FTL Driver Overview

- Simplified FTL design using Alibaba Open Channel (AOC) Command Set
- FTL Core: LOC < 50K
- A single code base to support kernel/user modes
- Accelerate regression test with simulation mode



Non-Contiguous Read Optimization



- 8KB/16KB read request
- LBAs are mapped to the same multi-plane page, but not contiguous
- Non-contiguous vector read is not support yet (HW limit)
- Read extra dummy data to avoid multiple 4KB reads

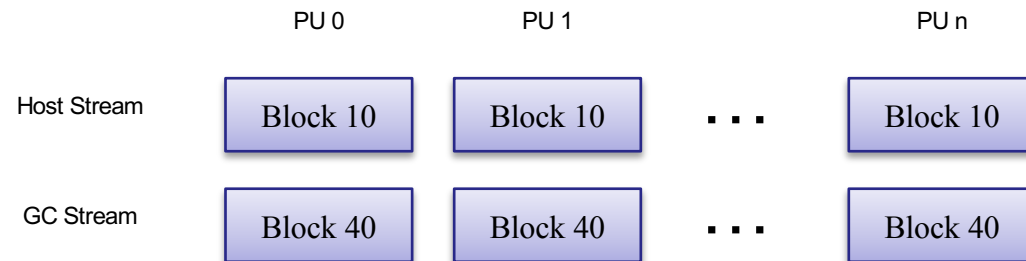


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Write Coalescing and Padding

- Reduce # of write commands for better IOPS and latency
- **Write Coalescing:** multiple 4KB/8KB host write requests are combined into a single write commands
- **Write Padding:** periodical padding to ensure host writes are translated into PU-aligned write commands

Host / GC Write Stream



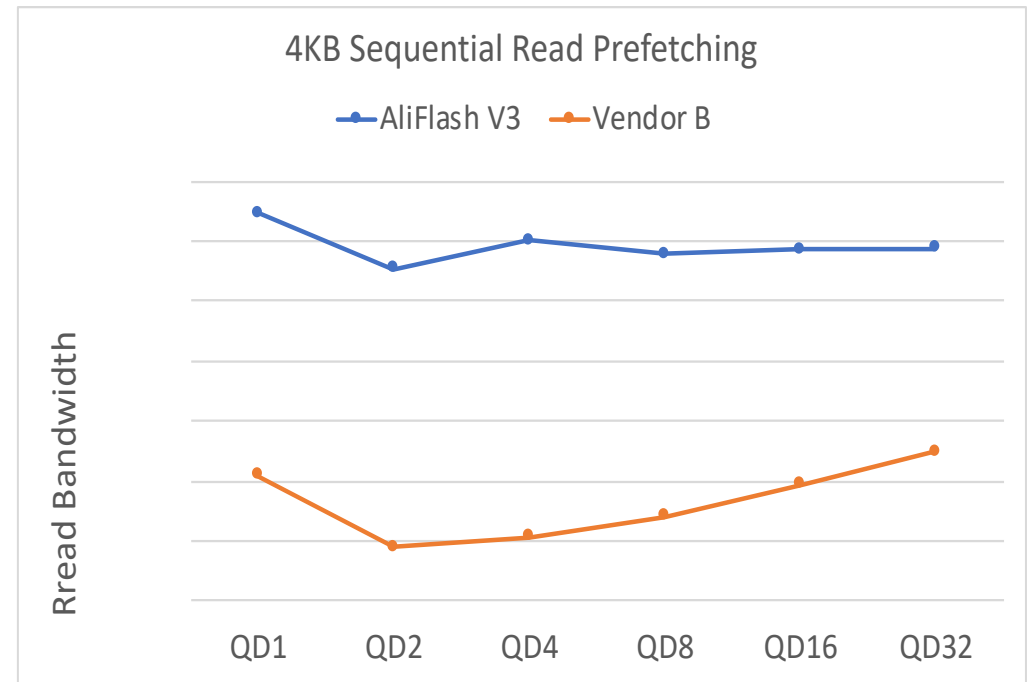
Optimized for low-QD
random write latency

- Up to 3 host streams and 1 GC stream
- Host and GC writes are scheduled independently
- Quota-based GC policy to balance host and gc writes
- Fewer free space → faster GC reads



Sequential Prefetching

- Sequential read IO patterns in some production workloads
- State machine based detector
- Host DRAM prefetching buffer
- Up to 5X read bandwidth improvement.





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Diagnostic Support

- 300+ runtime diagnostic parameters:
 - IOPS
 - Latency/QoS
 - GC/WL
 - Media Error
 - FTL driver parameters
 - FTL key data structures

```
#ocnvme lnmv status dfa
Basic Information:
Device:
Target Type:
Target Name:          osa
User Defined Name:    dfa
Power Cycles:         935
Power On Time:        3,046 hours
Firmware Revision:    OV1T2230
Driver Version:       1.3.8
Overprovision:         22.70
User capacity:        7501476528
Access mode:          ReadWrite
Atomic Write:         off
Dynamic Bad Blkcnts:  0

Lifetime Data Volumes:
Host Write Data:      2445.45 GB
Host Read Data:       0.03 GB
Total Write Data:     3042.36 GB
Lifetime Write Amplifier: 1.240

Realtime IO Statistics:
Read Bandwidth:       0.012 MB/s
Read IOPS:            0.000
Avg Read Latency:     0.098 ms
Write Bandwidth:      1125.916 MB/s
Write IOPS:           77.692
Avg Write Latency:    0.025 ms
GC Bandwidth:         32.569 MB/s
WL Bandwidth:         242.253 MB/s
Total Write Bandwidth: 1400.739 MB/s
Write Amplifier:      1.240
Raid5 Success Timers: 0
Raid5 Failed Timers: 0
Program Failed Timers: 0
Erase Failed Timers: 0
```



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Application Mode Support

- Fine-tune FTL driver parameters and policies for different usage scenarios
 - Database
 - Distributed Block Storage Service
 - ...
- Dynamic Configuration
 - Runtime adjustment support to a subset of driver parameters.



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Conclusion Remarks

- AliFTL: FTL driver implementation based on Alibaba open channel command set
- Read/write optimizations to reduce # of commands
- Multiple write stream optimized for low-QD random write latency
- Diagnostic support and application-based tuning
- Alibaba is open to industry collaboration



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THANK YOU

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